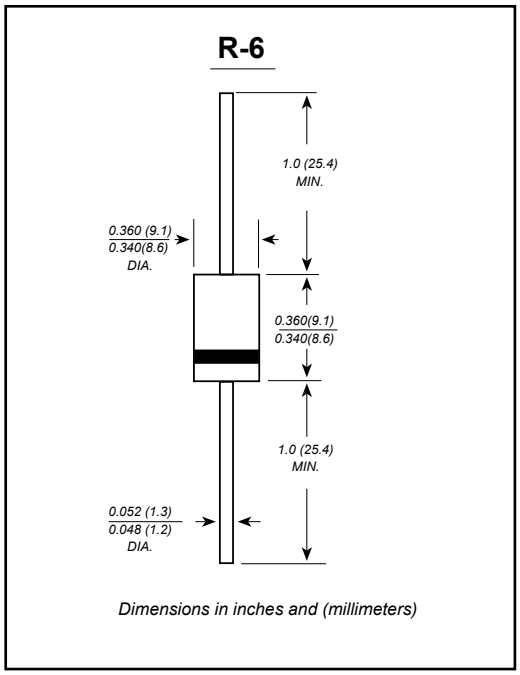
HER601 THRU HER608

HIGH EFFICIENT SILICON RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 6.0 Ampere

FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Ultra fast switching for high efficiency
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed: 250°C/10 seconds,0.375″(9.5mm) lead length, 5 lbs. (2.3kg) tension



MECHANICAL DATA

Case: R-6 molded plastic body
Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight:0.072 ounce, 2.05 grams

RoHS Compliant

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

Characteristic	Symbol	HER 601	HER 602	HER 603	HER 604	HER 605	HER 606	HER 607	HER 608	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	200	300	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	210	280	420	560	700	V
Average Rectified Output Current (Note 1) @T_A = 55°C	I_O	6.0								A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	200								A
Forward Voltage @I_F = 6.0A	V_{FM}	1.0				1.3	1.7			V
Peak Reverse Current @T_A = 25°C At Rated DC Blocking Voltage @T_A = 100°C	I_{RM}	10.0 100								μA
Reverse Recovery Time (Note 2)	t_{rr}	50					75			nS
Typical Junction Capacitance (Note 3)	C_j	100					65			pF
Operating Temperature Range	T_j	-65 to +150								°C
Storage Temperature Range	T_{STG}	-65 to +150								°C

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case
2. Measured with IF = 0.5A, IR = 1.0A, IRR = 0.25A. See figure 5.
3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

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RATINGS AND CHARACTERISTIC CURVES

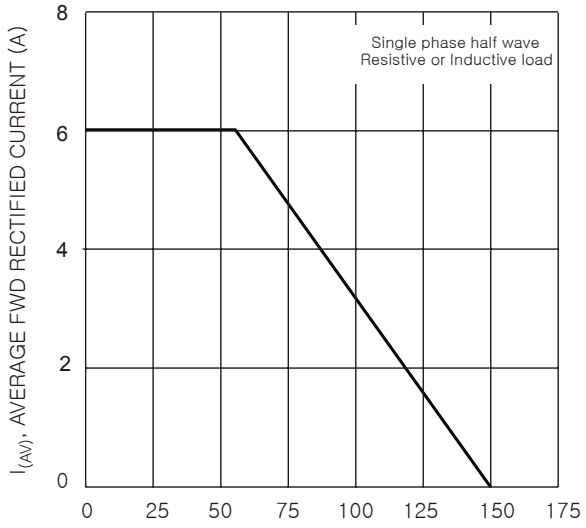


Fig. 1 Forward Current Derating Curve

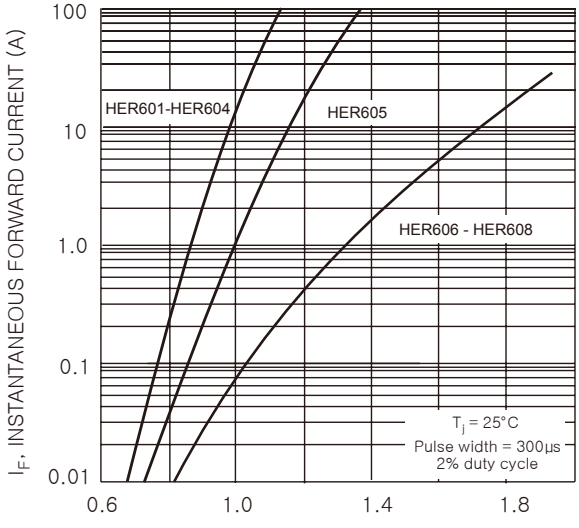


Fig. 2 Typical Forward Characteristics

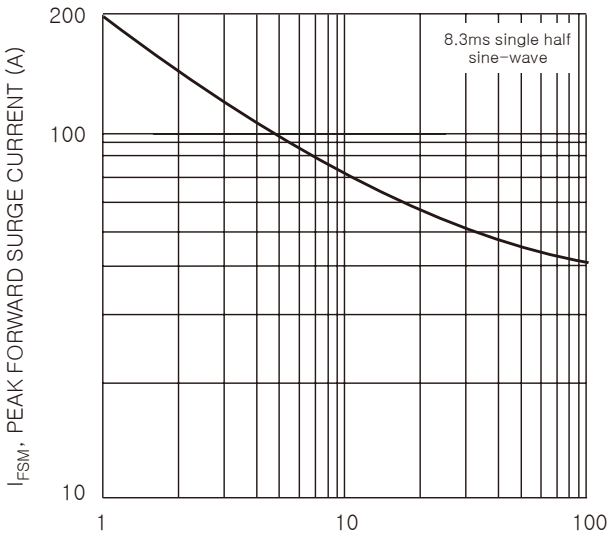


Fig. 3 Peak Forward Surge Current

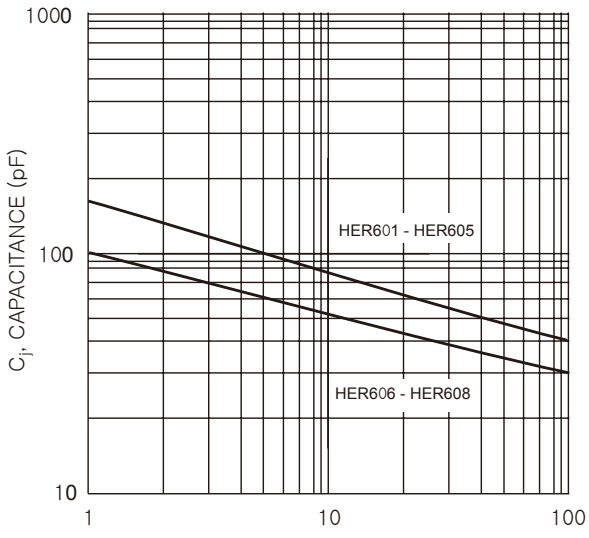
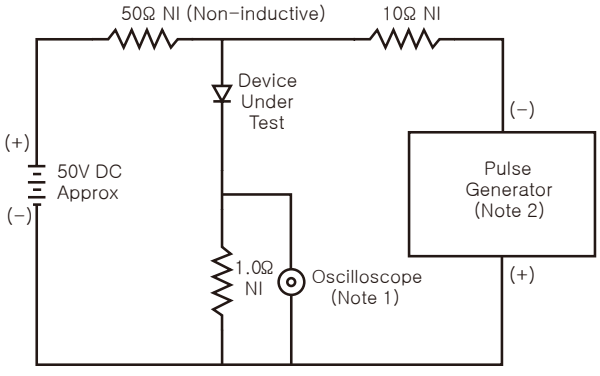
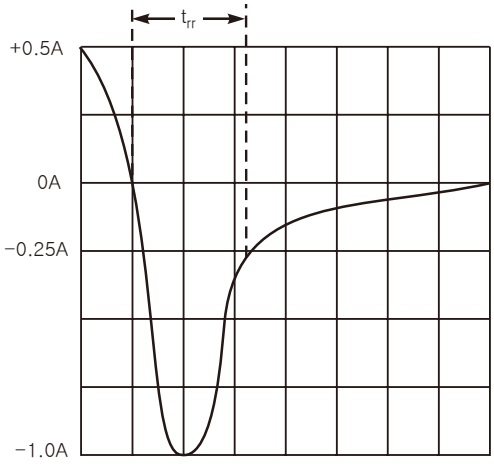


Fig. 4 Typical Junction Capacitance



Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
2. Rise Time = 10ns max. Input Impedance = 50Ω.



Set time base for 5/10ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit